NSN 5962-01-204-6382

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View Online at https://aerobasegroup.com/nsn/5962-01-204-6382 **Body Length:** Between 0.755 inches and 0.785 inches **Body Width:** Between 0.265 inches and 0.291 inches **Body Height:** Between 0.150 inches and 0.199 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Computer-display set an/uyq-2 (v) **Features Provided:** Bipolar and high speed and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:**

Rom

Memory Capacity:

Unknown

Test Data Document:

05869-726015-2 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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